8

2.Lab Report

Resistivity Measurements, Mobility Measurements

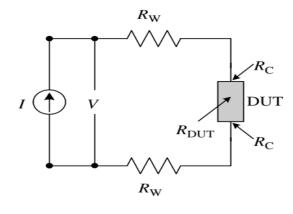
Soft of the

H Nareshkumar EE21M005

Resistivity measurements:

Theory:

1. Two terminal measurements



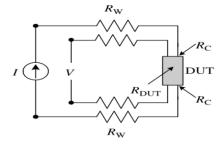
Rw: voltmeter internal resistance

Rc: contact resistance

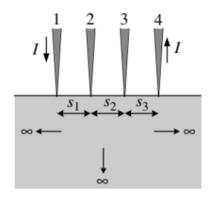
Rdut: resistance of device under test

$$R_T = V/I = 2R_W + 2R_C + R_{DUT}$$

2. four terminal measurements

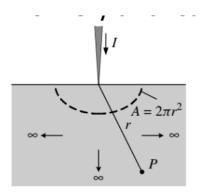


→ Pass the current from 1 and 4 probes and measure the voltage across the 2 and 3 terminals



s1,s2,s3 spacing between probes, for simplicity let us take spacing between them is equal

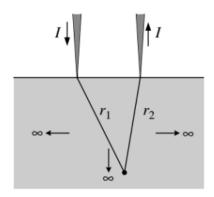
→ Let us take a simple case



Here r is the radius until p point

$$\mathscr{E} = J\rho = -\frac{dV}{dr}; \ J = \frac{I}{2\pi r^2}$$

$$\int_0^V dV = -\frac{I\rho}{2\pi} \int_0^r \frac{dr}{r^2} \Rightarrow V = \frac{I\rho}{2\pi r}$$



Apply superposition

$$V = \frac{I\rho}{2\pi r_1} - \frac{I\rho}{2\pi r_2} = \frac{I\rho}{2\pi} \left(\frac{1}{r_1} - \frac{1}{r_2} \right)$$

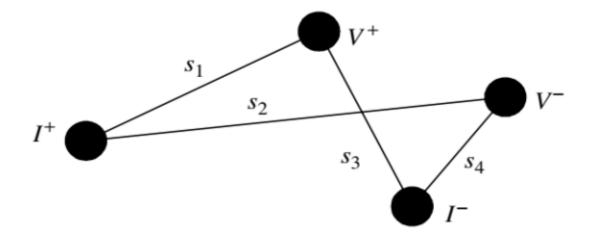
$$V_2 = \frac{I\rho}{2\pi} \left(\frac{1}{s_1} - \frac{1}{s_2 + s_3} \right)$$

$$V_3 = \frac{I\rho}{2\pi} \left(\frac{1}{s_1 + s_2} - \frac{1}{s_3} \right)$$

V = V2-V3

$$\rho = \frac{2\pi}{(1/s_1 - 1/(s_1 + s_2) - 1/(s_1 + s_2) + 1/s_3)} \frac{V}{I} = 2\pi s \frac{V}{I}$$

For a sample with finite thickness t



$$\mathscr{E} = J\rho = \frac{I\rho}{2\pi rt} = -\frac{dV}{dr}$$

$$\int_{V_{s1}}^{V_{s2}} dV = -\frac{I\rho}{2\pi t} \int_{s_1}^{s_2} \frac{dr}{r} \Rightarrow V_{s1} - V_{s2} = V_{12} = \frac{I\rho}{2\pi t} \ln\left(\frac{s_2}{s_1}\right)$$

$$V_{34} = -\frac{I\rho}{2\pi t} \ln\left(\frac{s_3}{s_4}\right) \qquad V = V_{12} - V_{34} = \frac{I\rho}{2\pi t} \ln\left(\frac{s_2 s_3}{s_1 s_4}\right)$$

• For colinear arrangement $s_1 = s_4 = s$ and $s_2 = s_3 = 2s$

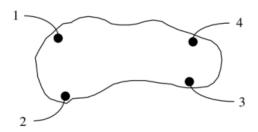
$$\rho = \frac{\pi t}{\ln(2)} \frac{V}{I} = 4.532t \frac{V}{I}$$

Van der pauw method:

→ If the samples are in arbitary shaped

Pass current from 1,2, and measure voltage between 3,4

Pass current from 2,3 and measure voltage between 1,4



$$R_{12,34} = \frac{V_{34}}{I_{12}}$$
 $\rho = \frac{\pi}{\ln(2)} t \frac{(R_{12,34} + R_{23,41})}{2} F$

$$e^{-\frac{\pi t R_{12,34}}{\rho}} + e^{-\frac{\pi t R_{23,41}}{\rho}} = 1$$

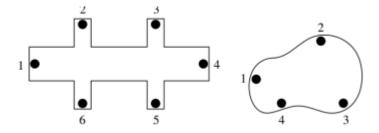
Hall effect

$$\mathbf{F} = q(\mathcal{E} + \mathbf{v} \times \mathfrak{B}) \qquad F_{y} = q(\mathcal{E}_{y} - \mathbf{v}_{x} \mathfrak{B}_{z})$$

$$\mathcal{E}_{y} = \mathbf{v}_{x} \mathfrak{B}_{z} = \frac{J_{x}}{q p_{0}} \mathfrak{B}_{z} = R_{H} J_{x} \mathfrak{B}_{z}, \qquad R_{H} \equiv \frac{1}{q p_{0}}$$

$$p_{0} = \frac{1}{q R_{H}} = \frac{J_{x} \mathfrak{B}_{z}}{q \mathcal{E}_{y}} = \frac{(I_{x}/wt) \mathfrak{B}_{z}}{q(V_{AB}/w)} = \frac{I_{x} \mathfrak{B}_{z}}{qt V_{AB}}$$

$$\mu_{p} = \frac{\sigma}{q p_{0}} = \frac{1/\rho}{q(1/q R_{H})} = \frac{R_{H}}{\rho}$$



Pass current from I and 4 terminals and measure the voltage between 2,6 or 3,5.

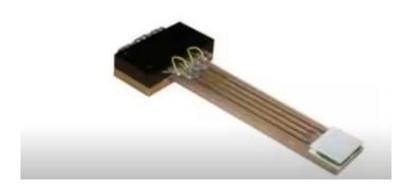
$$R_H = \frac{tV_{AB}}{I_x \mathfrak{B}_z} = \frac{tR}{\mathfrak{B}_z}$$
 $\mu_p = \frac{tR}{\rho \mathfrak{B}_z} = \frac{t\Delta R_{24,13}}{\rho \mathfrak{B}_z}$

Experiment

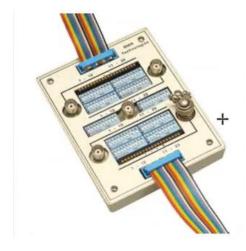
Hall measurements system: used to measuring the carrier mobility, carrier concentration and resistivity.

Here mobility, carrier concentration and resistivity are a function of temperature

Joule thomson refrigerator: this used for cooling and heating sample. Sample is placed on the heating plate operating range is from 80k to 580k.



Circuit breakout box: used to give power supply to joule thomson refrigerator, this circuit breakout interfaced with the temperature controller.



The filter/dryer setup: in order to reduce the temperature below the room temperature, Nitrogen Flows to the chamber form the metal wire.



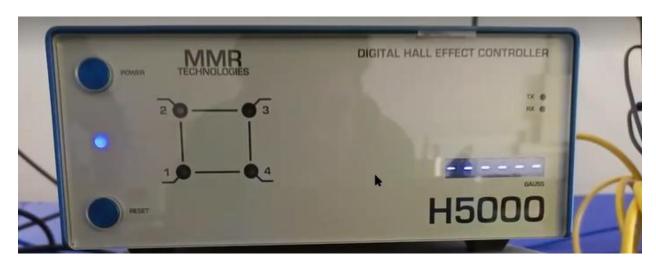
Dryer is connected to chamber. The complete chamber show below



Permanent magnet: in our lab we have 7500 gauss magnet.



Digital hall effect multiplier: this Digital hall effect multiplier is controlled with the help of software.

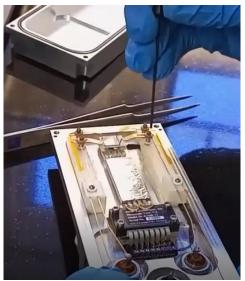


Here 4 point configuration given, we can supply current to any two probes and we have to measure the voltage between remaining two nodes.

Digital temperature controller(k2000):



- → Take si sample, thickness is 380 micrometer. 1 cm X 1 cm .this sample have to place in the cheark in the chamber.
- → After placing the sample, we have to see the electrical connections to four probes. Fix the sample with help of screw



→ close the chamber, joule thomson refrigerator ground connection have to connect with any one of four screw which was used to close the chamber.



→ From the Digital temperature controller(k2000) take 4 cables and connect as shown below. This cables number must be matched.



- → Switch on the Digital temperature controller, Digital hall effect controller.
- → Turn on the vacume pump, which creates the vacume in chamber to remove the gases and dust particles in chamber. We reduce the vacume below 40 m tor.



→ Place the chamber in between the permanent magnet



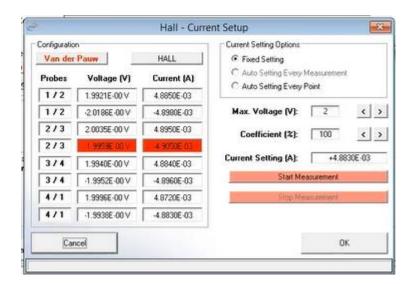
- → Open the software Mmr technology
- → We are using comm4 and comm5 for communications.

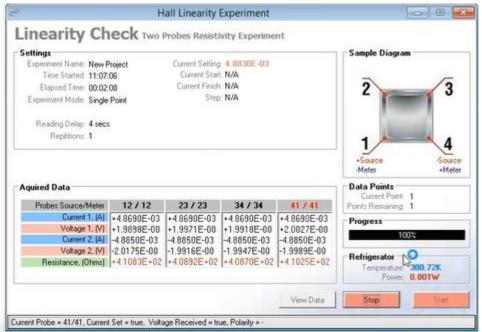


→ First linearity check
Applied current upper limit is 10mA, and voltage can be upto 2 volts.



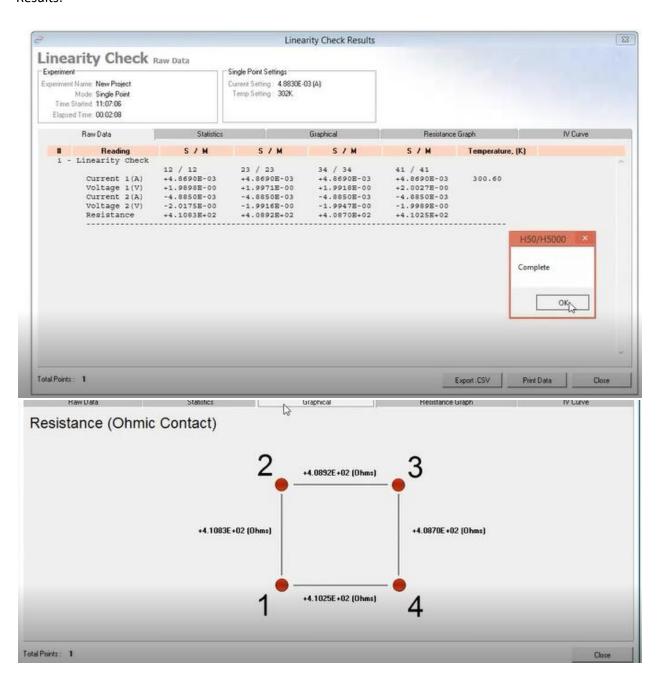
→ For single point current





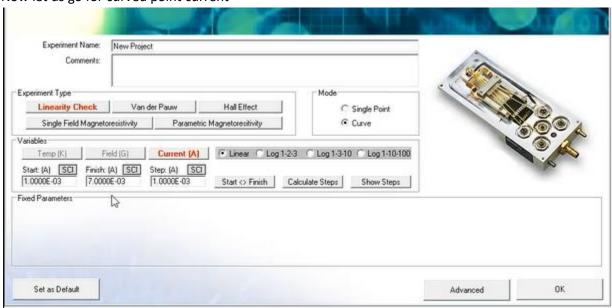
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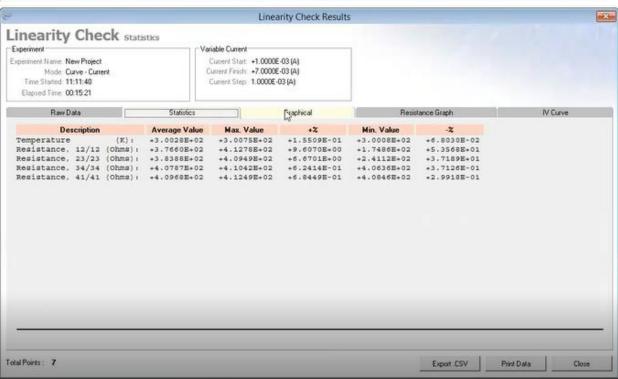
Results:

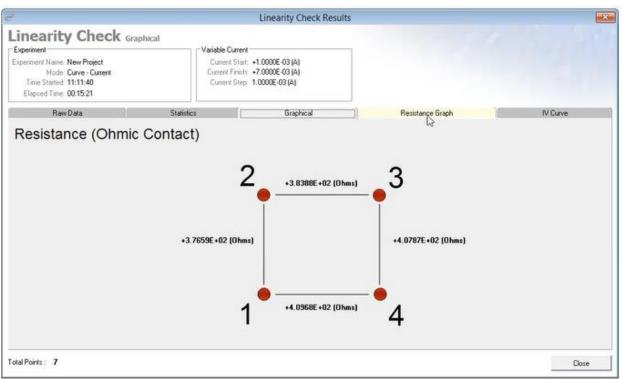


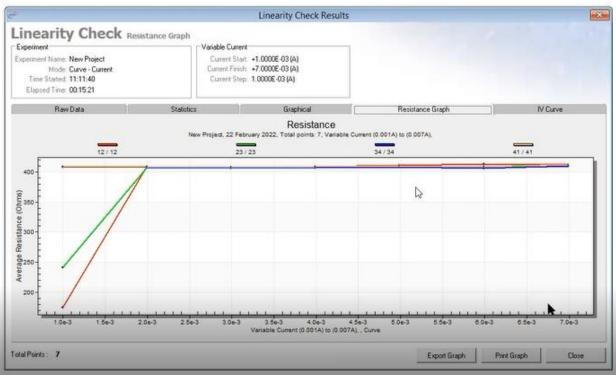
→ Now let us go for curved point current

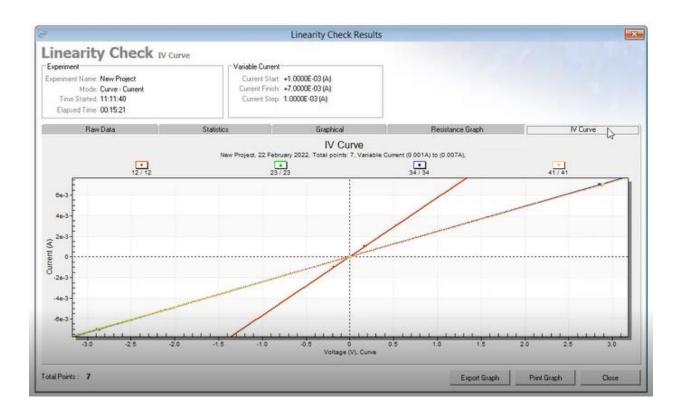
→



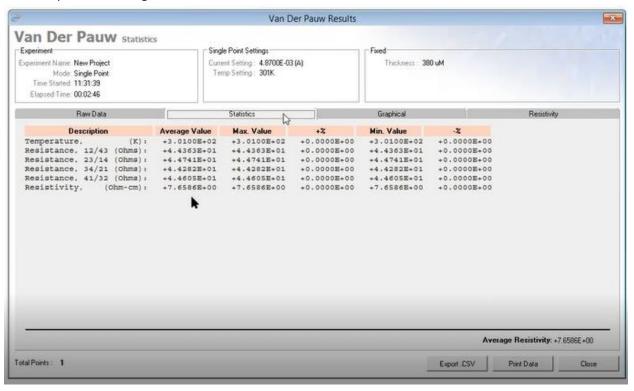


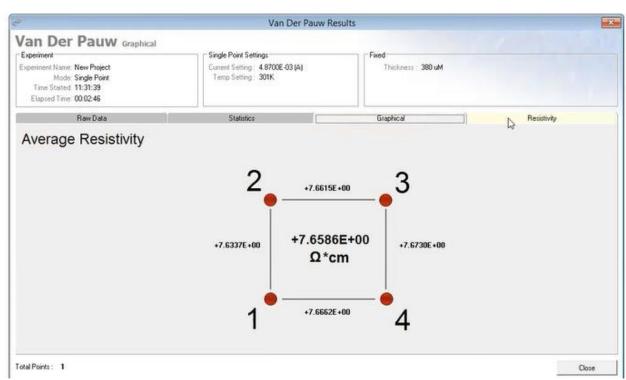




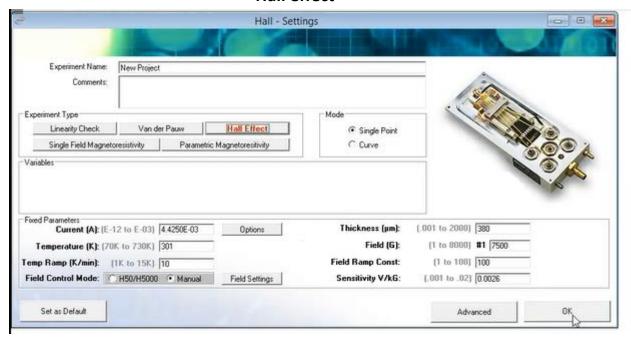


Now temperature changed from 300 k to 301 k

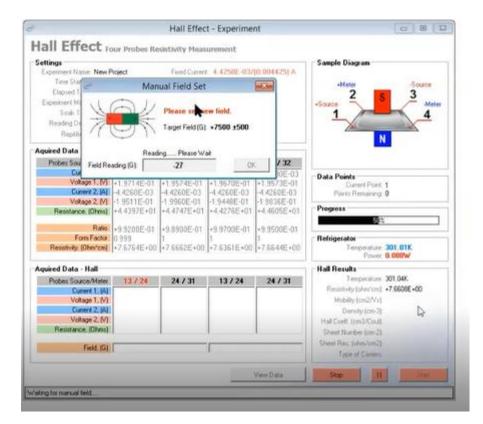




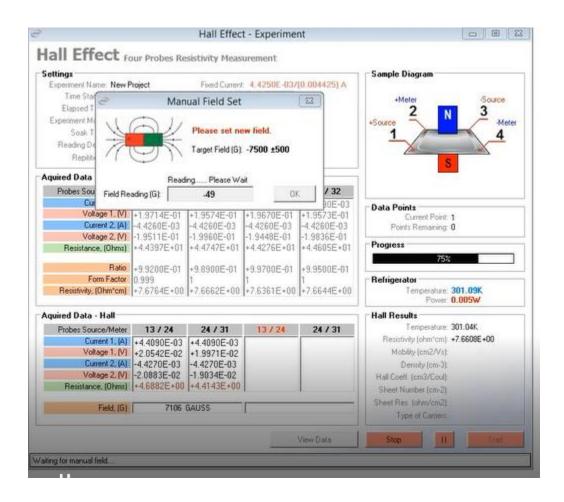
Hall effect



When the above message pops up, need to apply magnetic field.



When the above message pops up , we need to reverse the magnetic field direction



Hall effect results:

